



1N4001 1N4002 1N4003 1N4004 1N4005 1N4006 1N4007 DO-41

Specifications

1N4001 1N4002 1N4003 1N4004 1N4005 1N4006 1N4007 DO-41

1A General purpose diode

1.High efficiency, Low VF

2.High current capability

3.High reliability

4.ROHS

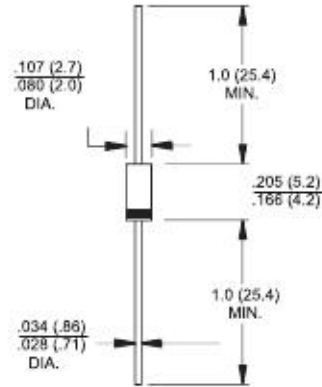
Features

- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode end
- ✧ High temperature soldering guaranteed: 260 °C /10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Weight: 0.35 gram

1N4001 - 1N4007 1.0 AMP. Silicon Rectifiers DO-41



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	1N 4001	1N 4002	1N 4003	1N 4004	1N 4005	1N 4006	1N 4007	BY 133	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	1300	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	910	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	1300	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length @ $T_A = 75^\circ\text{C}$	$I_{(AV)}$	1.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30								A
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.0								V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	I_R	5.0 50								uA uA
Maximum Full Load Reverse Current, Full Cycle Average .375" (9.5mm) Lead Length @ $T_A = 75^\circ\text{C}$	HT_{IR}	30								uA
Typical Junction Capacitance (Note 1)	C_j	10								pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	65								°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150								°C

Notes: 1. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.
2. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.